

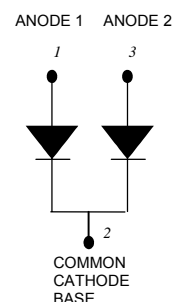
## MUR2020WT ULTRAFAST PLASTIC RECTIFIER

### Applications:

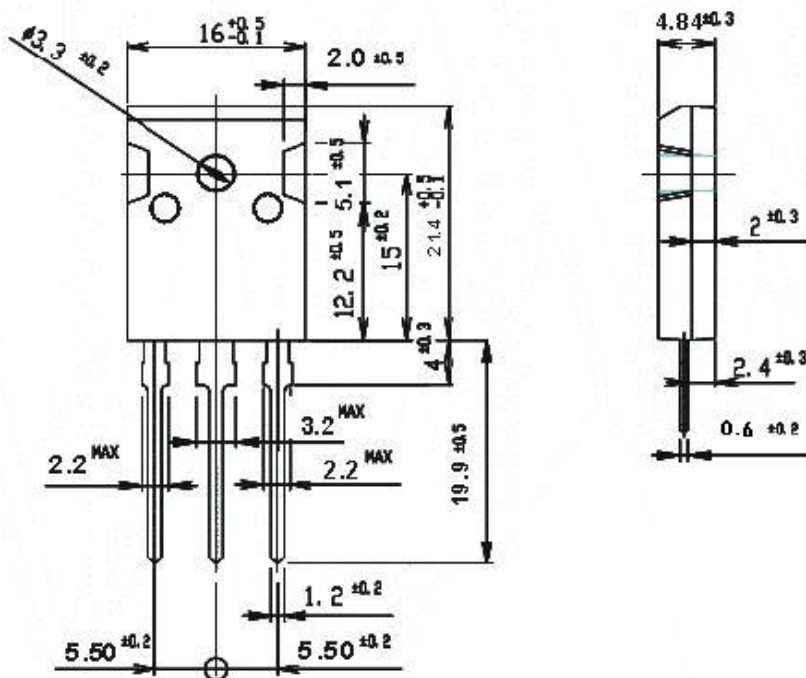
- Switching Power Supply
- Power Switching Circuits
- General Purpose

### Features:

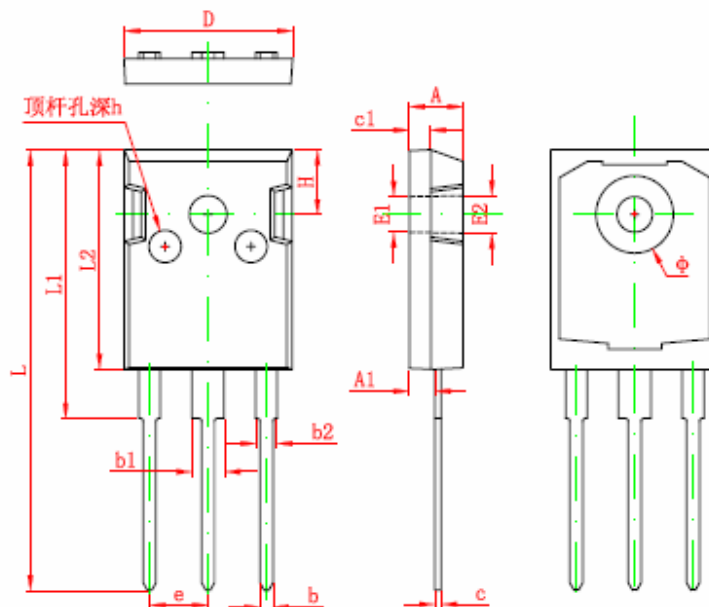
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



### Mechanical Dimensions: In mm/Inches



### OPTION 1(SR)

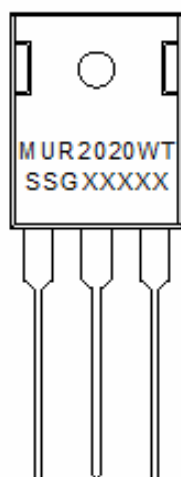


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF		0.138 REF	
E2	3.600 REF		0.142 REF	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
phi	7.100	7.300	0.280	0.287
e	5.450 TYP		0.215 TYP	
H	5.980 REF		0.235 REF	
h	0.000	0.300	0.000	0.012

**OPTION 2(CJ)**

**TO-247AD**

**Marking Diagram:**



Where XXXXX is YYWWL

MUR = Device Type  
 20 = Forward Current (20A)  
 20 = Reverse Voltage (200V)  
 WT = Configuration  
 SSG = SSG  
 YY = Year  
 WW = Week  
 L = Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
MUR2020WT	TO-247AD (Pb-Free)	30 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @ $T_c=85^\circ\text{C}$ , rectangular wave form	20	A
Max. Peak One Cycle Non-Repetitive Surge Current (Per leg)	$I_{FSM}$	8.3ms, Half Sine pulse	100	A

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop(Per leg)*	$V_{F1}$	@ 10A, Pulse, $T_J = 25^{\circ}\text{C}$	1.2	V
	$V_{F2}$	@ 10A, Pulse, $T_J = 125^{\circ}\text{C}$	1.0	V
Max. Reverse Current*	$I_{R1}$	@ $V_R = \text{rated } V_R$ $T_J = 25^{\circ}\text{C}$	10	$\mu\text{A}$
	$I_{R2}$	@ $V_R = 0.8 V_R$ $T_J = 125^{\circ}\text{C}$	100	$\mu\text{A}$
Max. Reverse Recovery Time	$t_{rr}$	$I_F=500\text{mA}$ , $I_R=1\text{A}$ , and $I_{rm}=250\text{mA}$	35	ns

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	$^{\circ}\text{C}$
Max. Storage Temperature	$T_{stg}$	-	-55 to +150	$^{\circ}\text{C}$
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	5.0	$^{\circ}\text{C}/\text{W}$
Approximate Weight	wt	-	6.7	g
Case Style	TO-247AD			

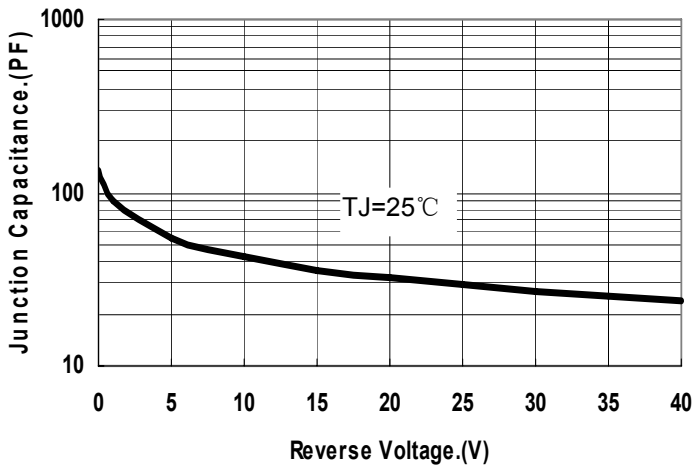


Fig.1-Typical Junction Capacitance

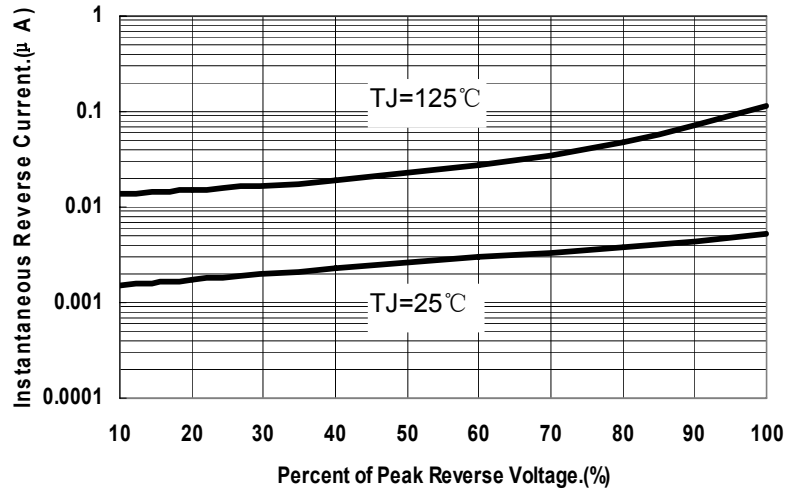


Fig.2-Typical Reverse Characteristics

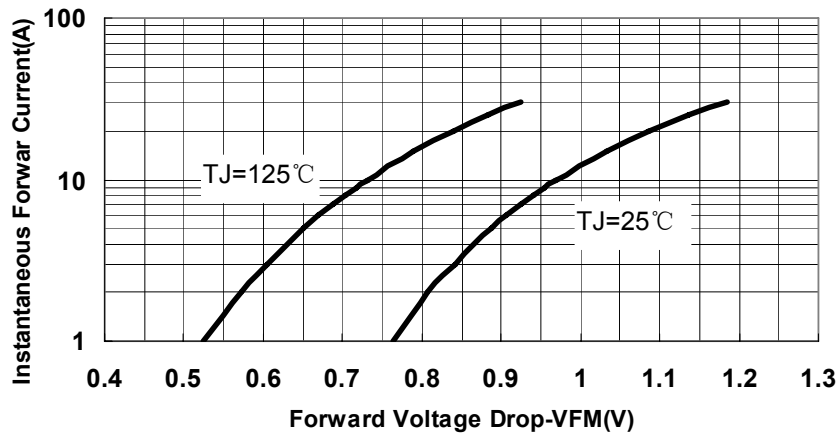


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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